



Infrared stealth property based on semiconductor (M)-to-metallic (R) phase transition characteristics of W-doped VO₂ thin films coated on cotton fabrics



Zhiping Mao^{*}, Wei Wang, Ying Liu, Linping Zhang^{*}, Hong Xu, Yi Zhong

Key Laboratory of Science & Technology of Eco-Textile (Ministry of Education), Donghua University, Shanghai 201620, PR China

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ABSTRACT

The infrared stealth fabric was prepared using W-doped VO₂ (M) paints by the coating technology. The thermochromic W-doped VO₂ (M) was synthesized through hydrolysis method and two-step calcinations under N₂ atmosphere. The powders were evaluated by scanning electron microscopy, X-ray diffraction patterns and differential scanning calorimetry. The infrared emissivity of coated cotton fabric was measured by IR-2 Infrared Emissometer, which was as low as 0.752. The low infrared radiation intensity for coated cotton fabric was detected using the infrared imaging systems above the phase temperature of W-doped VO₂ (M). The results indicated that the W-doped VO₂ (M) thin films exhibited thermal infrared stealth performance, which could adapt to the surroundings spontaneously.

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1. Introduction

The development of infrared surveillance technology in modern world had a significant effect on military personnel and equipment with an effective concealment [1]. Generally, objects and human beings were exposed easily under the infrared detectors due to the high emissivity. Therefore, low-emissivity materials became the focus of IR stealth technology in many countries [2]. However, emissivity of outside environment was not constant due to the temperature, moisture, solar intensity and cloud cover [3,4]. The objects were invisible for infrared sensitive viewing devices under the protection of materials with low emissivity in certain times; but they could be re-exposed when conditions altered. Hence, it is necessary to obtain a sort of material whose emissivity was adaptable to the surroundings spontaneously.

Vanadium dioxide of monoclinic structure VO₂ (M) is regarded as the most important and promising material, since it exhibits phase transition at transition temperature T_c = 68 °C, with dramatic changes of optical properties in IR area [5]. Vanadium dioxide (VO₂) has many different allotropic phases including VO₂(R), VO₂(M), VO₂(B), VO₂(A), VO₂(C) and VO₂(D) [6–8]. VO₂ (B) is a metastable allotropic phase, which can transform to the more stable rutile structure VO₂ (R) by heating treatment, then became monoclinic VO₂ (M) after the cooling process [9]. The rest metastable polymorphs VO₂(A), VO₂(C) and VO₂(D) were less reported comparatively [10]. In particular, most of the studies focus on the monoclinic VO₂ (M) due to its thermochromic

properties [5]. Below the transition temperature (T_c), monoclinic VO₂ (M) is a semiconductor, and above T_c, it becomes a rutile structure VO₂(R) which is metallic. This phase transition is fully reversible and associates with dramatic changes in electrical, magnetic and optical properties [11–13]. Moreover, T_c of VO₂ can be tuned to ambient temperature by doping with W, Nb, Mo and Ti for practical application [14–19]. Tungsten is one of the most effective dopant [14,15]. Therefore, with such properties, VO₂ material can be considered as a promising candidate for a variety of potential applications such as energy-efficient window coatings [20], thermal sensors [21], cathode materials for reversible lithium batteries [22], electrical and infrared light switching device [23,24].

However, there were few reports about the infrared stealth property of VO₂ in the literatures. Among them, Guinneton pointed out there was a fall of 60% in normal integrated emissivity of VO₂ thin film between 8 and 12 μm, which made it possible to be a sort of potential material for infrared stealth [11]. Moreover, the adaptive infrared camouflage property of VO₂ coated fabric was reported by Dongqing Liu [25]. Results showed that infrared emissivity in 8–14 μm of VO₂ coated fabric was 0.82, which decreased by only about 0.1 during the phase transition. Therefore, infrared stealth performance of VO₂ must be improved for practical application.

In this paper, W-doped VO₂ (M) paints were used to prepare coated cotton fabric. The VO₂ (M) samples with various W doping contents were prepared via hydrolysis of vanadyl sulfate mixed with different amounts of sodium tungstate dehydrate, followed by two-step thermal treatment under N₂ atmosphere. The infrared stealth property of cotton fabric with W-doped VO₂ films was measured by IR-2 Infrared

^{*} Corresponding authors. Tel.: +86 21 67792720; fax: +86 21 67792707.
E-mail addresses: zhpmiao@dhu.edu.cn (Z. Mao), zhang_lp@dhu.edu.cn (L. Zhang).

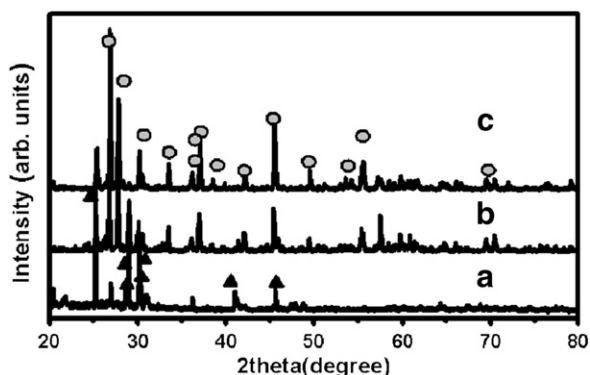


Fig. 1. XRD patterns of W-doped VO₂ samples: (a) W-doped VO₂ (B); (b) VO₂ (M); (c) W-doped VO₂ (M).

Emissometer and Infrared imaging systems. Results indicated that W-doped VO₂ (M) had low infrared emissivity and infrared radiation intensity, which exhibited an outstanding performance of thermal infrared stealth.

2. Material and methods

2.1. Materials

Vanadyl sulfate hydrate (VOSO₄, 98%) was purchased from Shanghai Huating Chemical Factory Limited Company. Sodium hydrogen carbonate (NaHCO₃), sodium tungstate dihydrate (Na₂WO₄·2H₂O) and absolute ethyl alcohol (CH₃CH₂OH) were purchased from Sinopharm Chemical Reagent Limited Company. Water borne polyurethane (PU-3645) was purchased from Sansheng Limited Company. The cotton fabric with a density of 300 g/m² was provided by Huafang Limited Company.

2.2. Preparation of W-doped VO₂ (M) powders

The synthesis method of W-doped VO₂ (B) with different amounts of tungsten was similar to hydrothermal process reported by Jianqiu Shi et al. [26]. In a typical synthesis, vanadyl sulfate hydrate (0.15 mol) and stoichiometric sodium tungstate dihydrate with different W/(W + V) molar percents (0%, 0.5%, 1.0%, 1.5%) were dispersed in 100 ml deionized water by vigorous stirring to form a green solution. Meanwhile, sodium hydrogen carbonate (0.3 mol) was dissolved in 100 ml deionized water and dropped into the above mixture. After stirring for an hour, the resulting brown powders were filtered and washed with deionized water till no sulfate was tested. Then, resulted samples

Table 1
W molar percent of W-doped VO₂ in solutions and in the prepared solids.

W/(W + V) in solutions (%)	W/(W + V) in prepared solids (%)	Standard deviation
0	0	0
0.5	0.489	0.0017
1.0	0.971	0.0016
1.5	1.480	0.0019

were washed by absolute ethanol and dried at 40 °C under vacuum. The VO₂ (B) powders with different W-doped contents were prepared by subsequent calcination at 800 °C under N₂ atmosphere. Finally, VO₂ (M) powders with different W-doped contents were obtained through the secondary heat treatment at 500 °C under N₂ atmosphere in the atmosphere furnace. The products were named as x-W-doped VO₂, wherein x represented W/(W + V) molar percent.

2.3. Preparation of thermochromic coatings

The VO₂ solids with different molar ratios of W were mixed with zirconia beads, the dispersant and deionized water, at a weight ratio of 1:50:0.1:10 in a planetary ball mill, stirring for 60 min at a rotational speed 800 r/min. Then, W-doped VO₂ suspension was carefully embedded into the water borne polyurethane (PU-3645) with vigorous stirring for 2 h. The above solution was deposited on the cotton fabric by the automatic coater. The wet coating thickness controlled by thickness controller was 300 μm. Then the obtained W-doped VO₂ coated fabric was dried at 150 °C for 5 min with a shaping machine. As control experiment, pure water borne polyurethane coating on the fabric was also prepared.

2.4. Characterization

Wide angle powder X-ray diffraction measurements (WXR) were carried out using a Rigaku diffractometer (Rigaku Ltd, 40 KV, 200 mA, Cu Kα, λ = 1.54056 Å). Energy Dispersion X-ray analysis (EDX) was determined on a IE 300X instrument (Oxford, United Kingdom) operating at 7.5 kV. The obtained data was quantified using Oxford Software, with pure metallic vanadium and tungsten used as standards. Scanning Electron Microscopy (SEM) was carried out on a JSM-5600LV scanning microscope (JEOL, Japan) to determine the morphology of samples at a microscale. Differential scanning calorimetry (DSC) was performed on a DSC204F1 system (NETZSCH, Germany) to measure the phase-transition temperature of W-doped VO₂ (M). Each sample was tested in air atmosphere from room temperature to 150 °C, with a heating rate of 10 °C/min. The infrared stealth durability of coated fabrics was

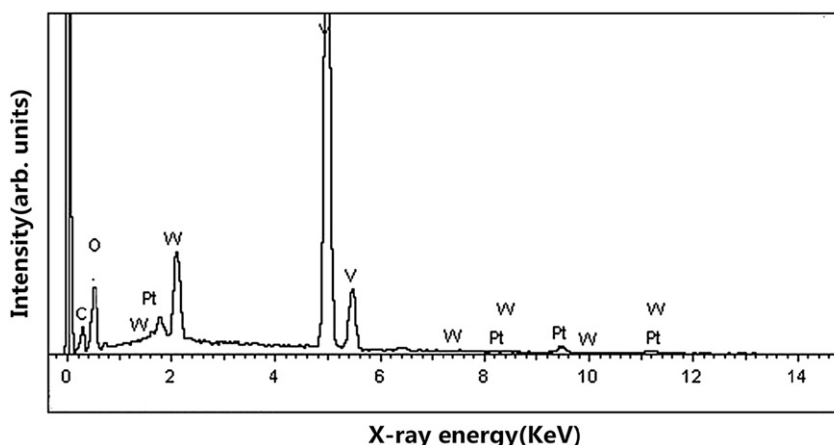


Fig. 2. EDX pattern of 1.0%-W-doped VO₂ (M) powders.

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